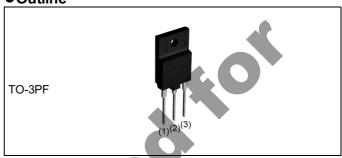
Nch 600V 30A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	0.130Ω
I _D	±30A
P _D	86W

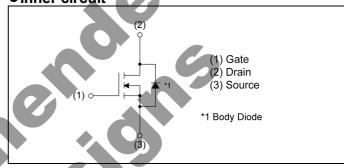
●Outline



Features

- 1) Low on-resistance.
- 2) Ultra fast switching speed.
- 3) Parallel use is easy.
- 4) Pb-free lead plating; RoHS compliant

•Inner circuit



Packaging specifications

	3	
	Packing	Tube
	Reel size (mm)	-
Time	Tape width (mm)	-
Туре	Quantity (pcs)	360
	Taping code	C8
	Marking	R6030KNZ

Application

Switching

● Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain - Source voltage		V_{DSS}	600	V
Continuous drain current (T _c = 25	I _D *1	±30	Α	
Pulsed drain current	l _{DP} *2	±90	Α	
Cata Carria valtaria	static	\/	±20	V
Gate - Source voltage	AC(f>1Hz)	V_{GSS}	±30	V
Avalanche current, single pulse	·	I _{AS}	5.2	Α
Avalanche energy, single pulse		E _{AS} *3	636	mJ
Power dissipation (T _c = 25°C)	P _D	86	W	
Junction temperature	T _j	150	°C	
Operating junction and storage to	emperature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Downwortow	Cymah al	Values			1.1:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *4	-	-	1.5	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	40	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	4	265	°C

● Electrical characteristics (T_a = 25°C)

Conditions Conditions		Values		Unit		
Symbol	Conditions	Min.	Тур.	Max.	Offic	
V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	1	V	
	$V_{DS} = 600V, V_{GS} = 0V$					
I _{DSS}	$T_j = 25^{\circ}C$	-	-	100	μΑ	
	$T_j = 125^{\circ}C$	-	-	1000		
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA	
V _{GS(th)}	$V_{DS} = 10V, I_{D} = 1mA$	3	-	5	V	
	V _{GS} = 10V, I _D = 14.5A					
R _{DS(on)} *5	T _j = 25°C	-	0.115	0.130	Ω	
	T _j = 125°C	-	0.26	-		
R_{G}	f = 1MHz, open drain	-	2.1	-	Ω	
	I _{DSS} I _{GSS} V _{GS(th)}	$V_{(BR)DSS} V_{GS} = 0V, I_{D} = 1 \text{mA}$ $V_{DS} = 600V, V_{GS} = 0V$ $T_{j} = 25^{\circ}C$ $T_{j} = 125^{\circ}C$ $V_{GS} = \pm 20V, V_{DS} = 0V$ $V_{GS(th)} V_{DS} = 10V, I_{D} = 1 \text{mA}$ $V_{GS} = 10V, I_{D} = 14.5 \text{A}$ $R_{DS(on)}^{*5} T_{j} = 25^{\circ}C$ $T_{j} = 125^{\circ}C$	$V_{(BR)DSS} V_{GS} = 0V, I_D = 1 mA $ $V_{DS} = 600V, V_{GS} = 0V$ $I_{DSS} T_j = 25 ^{\circ}C $ $T_j = 125 ^{\circ}C $ $V_{GS} = \pm 20V, V_{DS} = 0V $ $V_{GS(th)} V_{DS} = 10V, I_D = 1 mA $ $V_{GS} = 10V, I_D = 14.5A$ $R_{DS(on)}^{*5} T_j = 25 ^{\circ}C $ $T_j = 125 ^{\circ}C $ $T_j = 125 ^{\circ}C $ $T_j = 125 ^{\circ}C $		$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	

● Electrical characteristics (T_a = 25°C)

Darramatar	Cymah al	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	UIIIL	
Forward Transfer Admittance	Y _{fs} *5	$ Y_{fs} ^{*5}$ $V_{DS} = 10V, I_D = 15A$		20	-	S	
Input capacitance	C _{iss}	V _{GS} = 0V	-	2350			
Output capacitance	C _{oss}	V _{DS} = 25V	-	2000		pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	70	-		
Turn - on delay time	t _{d(on)} *5	$V_{DD} \simeq 300V$, $V_{GS} = 10V$	-(35	-		
Rise time	t _r *5	I _D = 15A	75	65	-	20	
Turn - off delay time	t _{d(off)} *5	$R_L \simeq 20\Omega$	-	100	-	ns	
Fall time	t _f *5	$R_G = 10\Omega$	-	50	-		

● Gate charge characteristics (T_a = 25°C)

Doromotor	Cymbal	Conditions)	Values		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*5}	V _{DD} ≈ 300V	1	56	1	
Gate - Source charge	Q _{gs} *5	I _D = 30A	-	18	-	nC
Gate - Drain charge	Q _{gd} *5	V _{GS} = 10V	-	23	-	
Gate plateau voltage	V _(plateau)	$V_{DD} \simeq 300V$, $I_D = 30A$	1	6.6	ı	V

^{*1} Limited only by maximum channel temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L \doteqdot 50mH, V_{DD}=50V, R_G=25 Ω , STARTING T_j=25°C

^{*4} T_C=25°C

^{*5} Pulsed

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Davamatav	Cymah al	Canditions	Values			Unit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Continuous forward current	I _S *1	T - 25°C	1	1	30	А
Pulse forward current	I _{SP} *2	T _C = 25°C	-	-	90	A
Forward voltage	V _{SD} *5	$V_{GS} = 0V, I_{S} = 30A$	-	-	1.5	V
Reverse recovery time	t _{rr} *5		-	517	-	ns
Reverse recovery charge	Q _{rr} *5	I _S = 30A di/dt = 100A/µs		9.6	-	μC
Peak reverse recovery current	I _{rrm} *5	- αναι – 100/4μ3		37	-	Α

● Typical transient thermal characteristics

Symbol	Value	Unit
R _{th1}	0.0865	
R _{th2}	0.469	K/W
R _{th3}	1.22	

Symbol	Value	Unit
C _{th1}	0.00598	
C _{th2}	0.0547	Ws/K
C _{th3}	1.09	

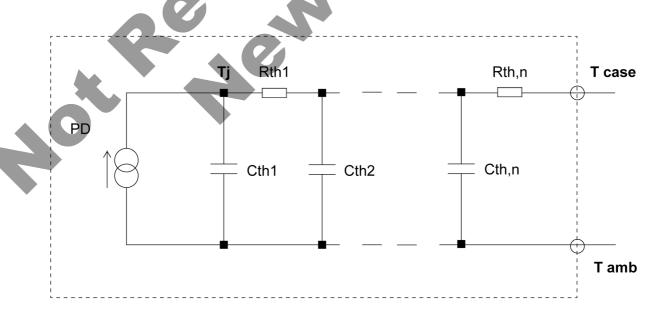


Fig.1 Power Dissipation Derating Curve

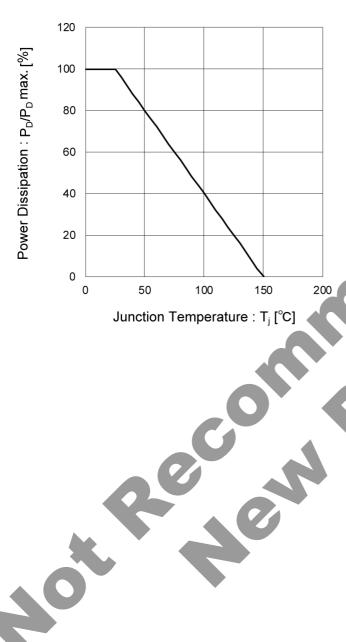


Fig.2 Maximum Safe Operatind Area

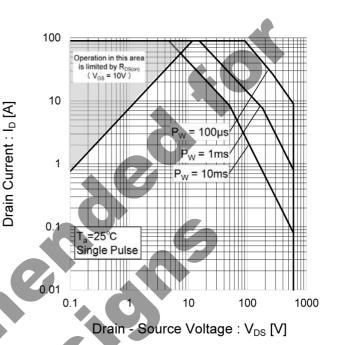
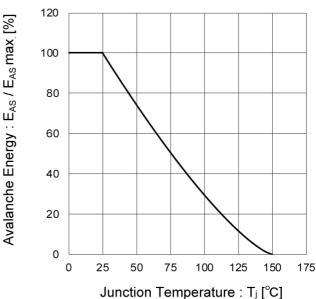
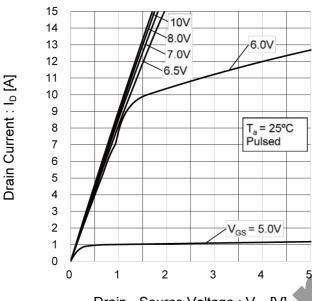


Fig.3 Avalanche Energy Derating Curve vs. Junction Temperature



ROHM

Fig.4 Typical Output Characteristics(I)



Drain - Source Voltage : V_{DS} [V]

Fig.5 Typical Output Characteristics(II)

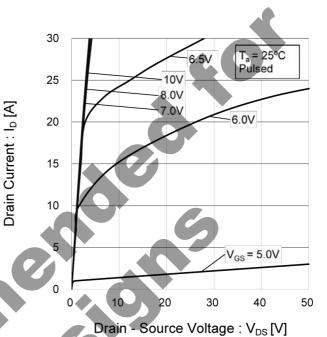


Fig.6 Breakdown Voltage vs.

Junction Temperature

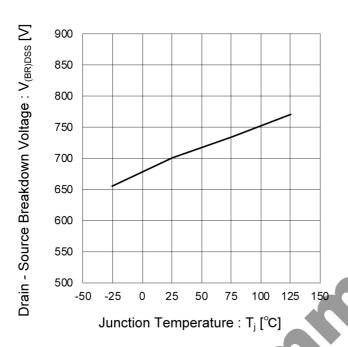


Fig.7 Typical Transfer Characteristics

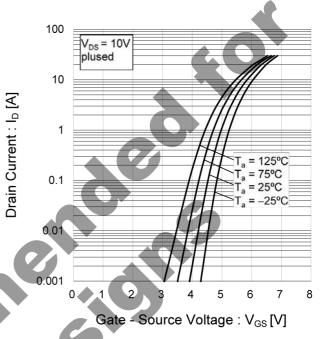


Fig.8 Gate Threshold Voltage vs.
Junction Temperature

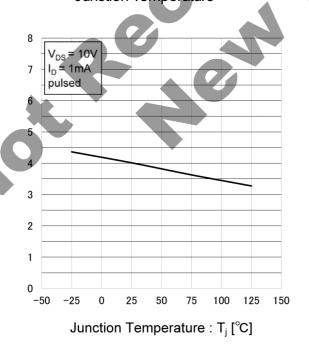
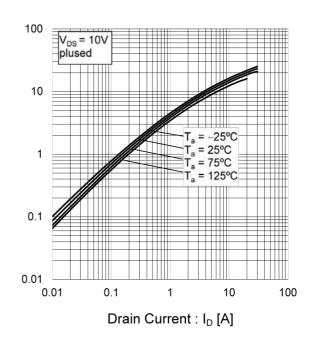


Fig.9 Forward Transfer Admittance vs.

Drain Current



Gate Threshold Voltage: V_{GS(th)} [V]

Transconductance : g_{fs} [S]

Fig.10 Static Drain - Source On - State Resistance vs. Gate Source Voltage

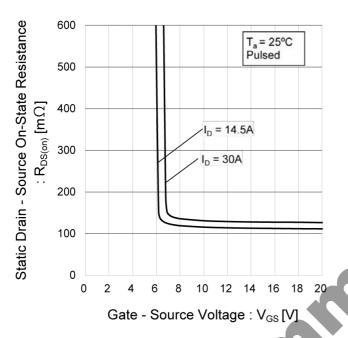


Fig.11 Static Drain - Source On - State Resistance vs. Junction Temperature

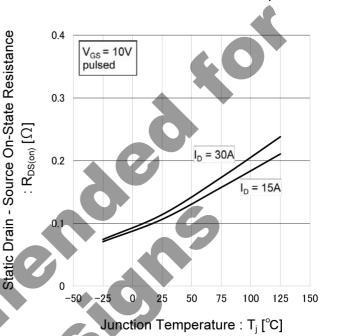


Fig.12 Static Drain - Source On - State Resistance vs. Drain Current(I)

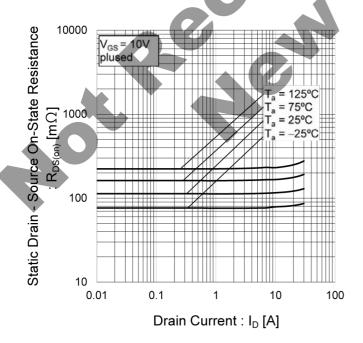


Fig.13 Typical Capacitance vs.
Drain - Source Voltage

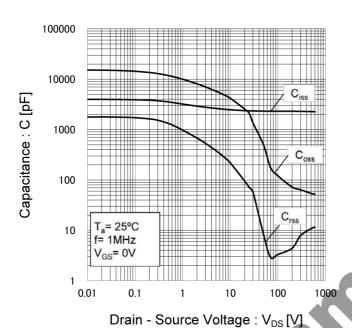


Fig.14 Switching Characteristics

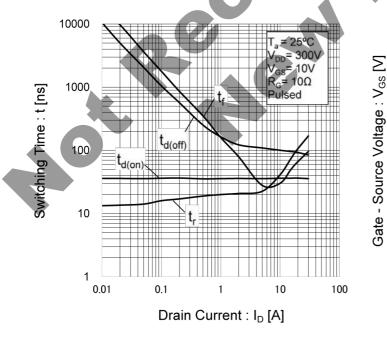


Fig.15 Dynamic Input Characteristics

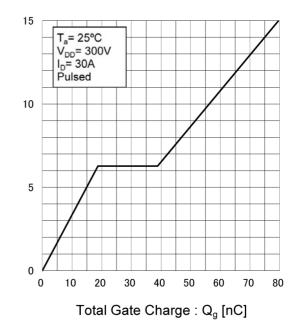
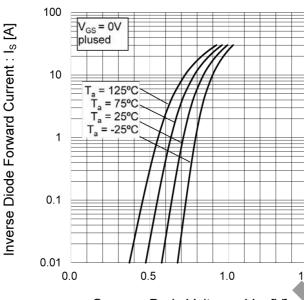
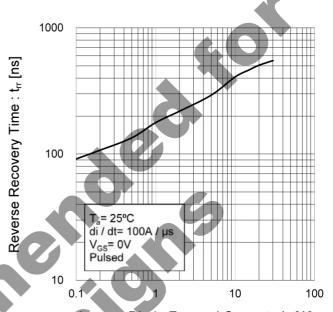


Fig.16 Inverse Diode Forward Current vs. Source - Drain Voltage



Source - Drain Voltage : V_{SD} [V]

Fig.17 Reverse Recovery Time vs.
Inverse Diode Forward Current



Inverse Diode Forward Current : I_S [A]

R6030KNZ Datasheet

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

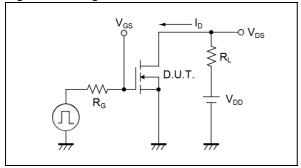


Fig.2-1 Gate Charge Measurement Circuit

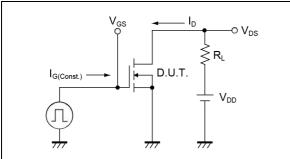


Fig.3-1 Avalanche Measurement Circuit

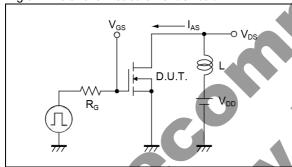


Fig.4-1 dv/dt Measurement Circuit

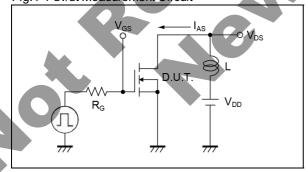


Fig.5-1 di/dt Measurement Circuit

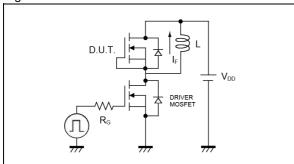


Fig.1-2 Switching Waveforms

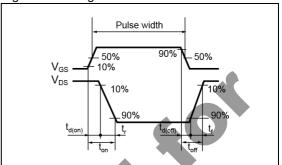


Fig.2-2 Gate Charge Waveform

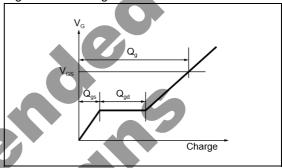


Fig.3-2 Avalanche Waveform

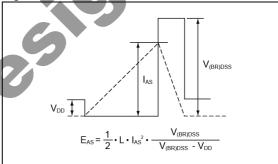


Fig.4-2 dv/dt Waveform

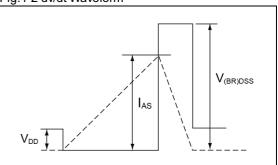
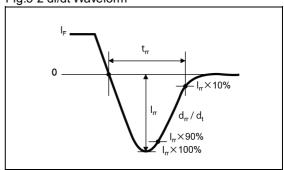
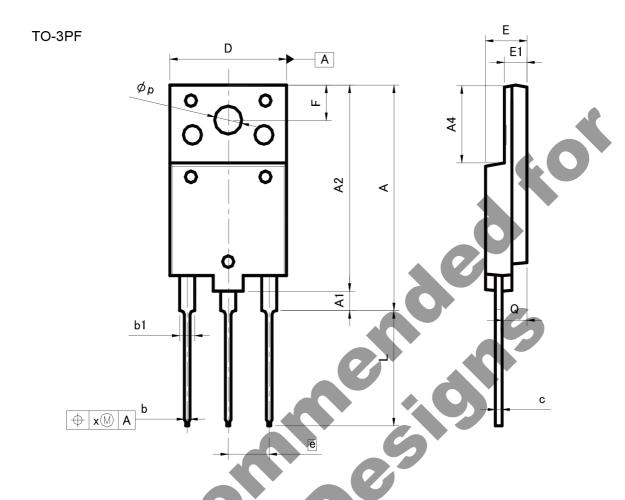


Fig.5-2 di/dt Waveform



Dimensions



DIM	MILIME		DIM		INC	HES
DIM	MIN	MAX	MIN	MAX		
A	26.30	26.70	1.035	1.051		
A1	2.30	2.70	0.091	0.106		
A2	26.30	26.70	1.035	1.051		
A4	9.80	10.20	0.386	0.402		
b	0.65	0.95	0.026	0.037		
b1	1.80	2.20	0.071	0.087		
С	0.80	1.10	0.031	0.043		
D	15.30	15.70	0.602	0.618		
E	5.30	5.70	0.209	0.224		
е	5.4	45	0.215	2:-2		
E1	2.80	3.20	0.110	0.126		
F	4.30	4.70	0.169	0.185		
L	14.60	15.00	0.575	0.591		
р	3.40	3.80	0.134	0.150		
Q	3.10	3.50	0.122	0.138		
х	-	0.50	9 — 0	0.020		

Dimension in mm/inches

Notice

Precaution on using ROHM Products

Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CL ACCIII	CLASS II b	CLASSIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSIII

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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- All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
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